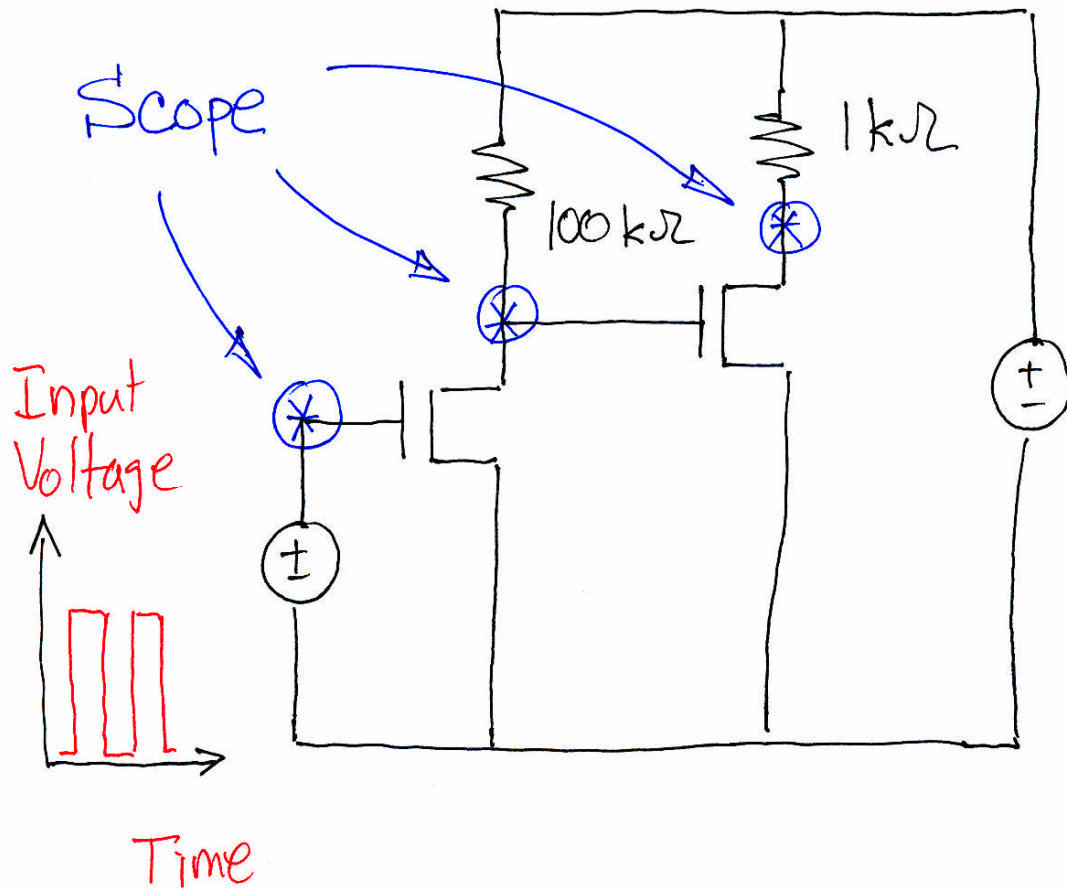


6.002 - Lecture 10

Time Does Matter

- Logic Gate Delays
- MOSFET Physics
- Capacitors, Inductors, Transformers
- First-Order ODE

Logic Gate Delays



Observe voltages as frequency increases.

Time Delays

Time Delays



Memory



Energy storage

E & M
Circuits
Mechanics
Fluidics
⋮

Memoryless^{*} Devices

Sources

Resistors

Ideal MOSFETs

Ideal Transformers

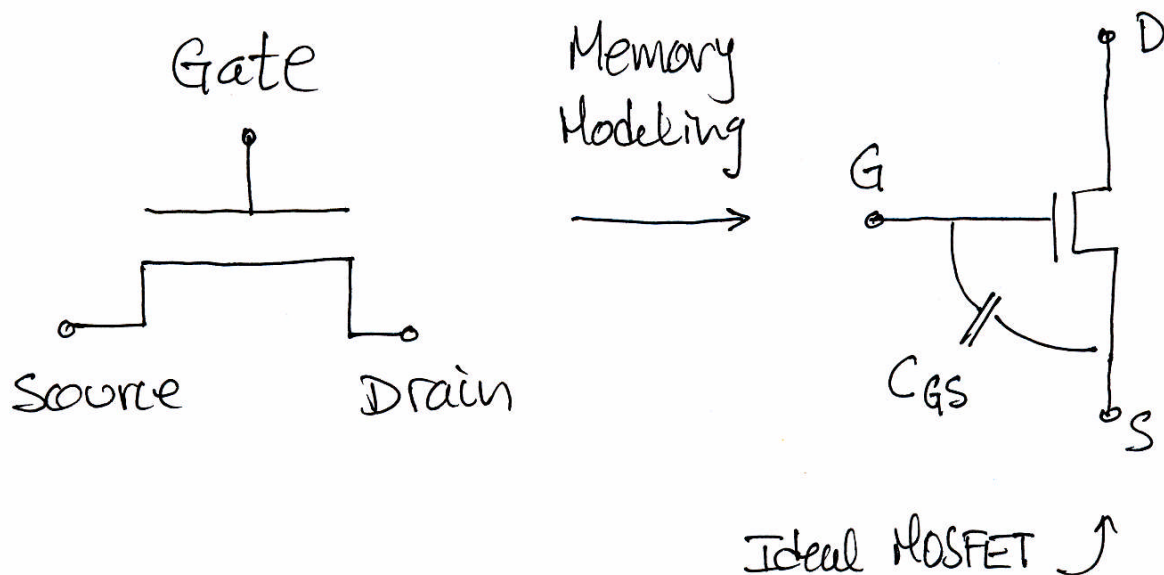
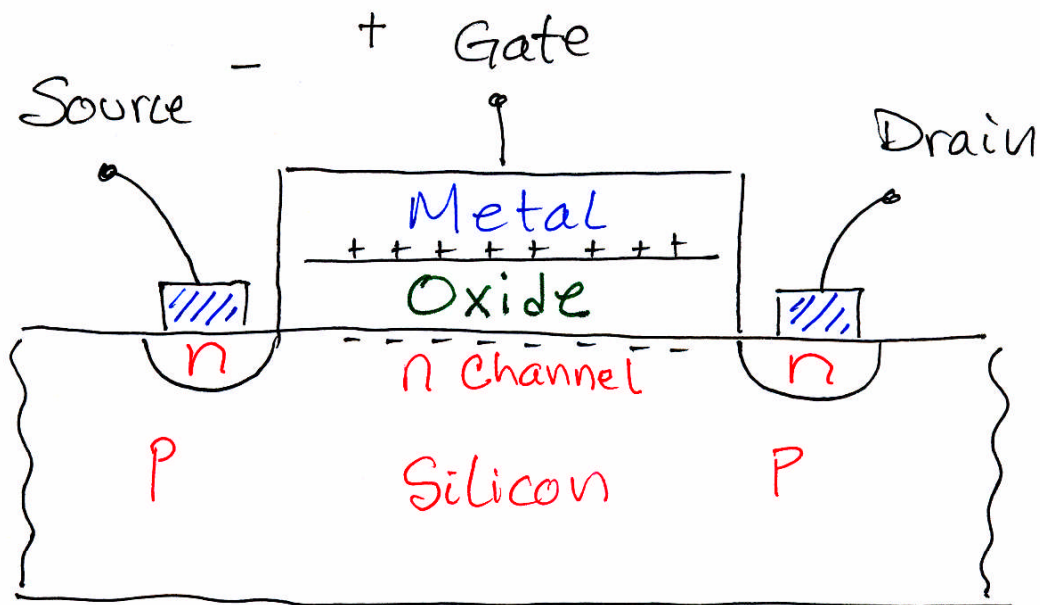
Memory Devices

Capacitors

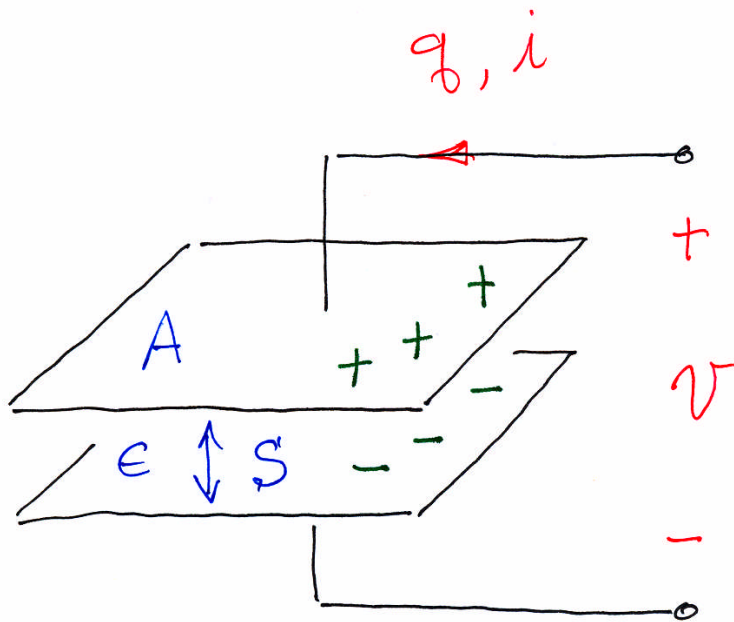
Inductors

* Not considering thermal memory!

MOSFET Physics



Ideal Capacitor



Farads

$$q = C V$$

Coulombs Volts

$$C = \frac{\epsilon A}{S}$$

$$q = \int_{-\infty}^t i dt \quad i = \frac{dq}{dt} = \frac{d}{dt}(Cv) = C \frac{dv}{dt}$$

Memory

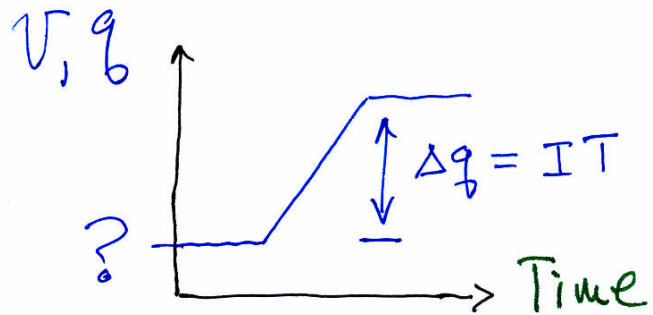
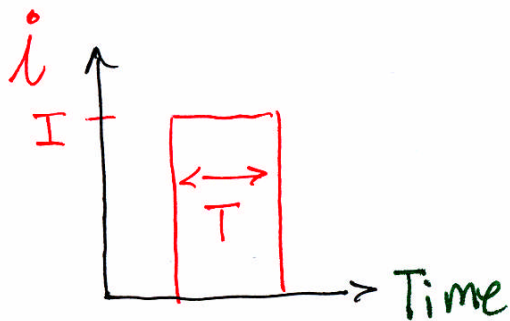
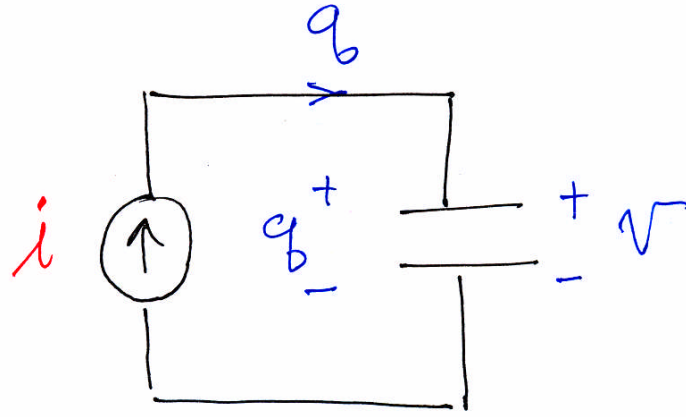
6.002

$$P = v i = C v \frac{dv}{dt} = \frac{d}{dt} \left(\frac{1}{2} C v^2 \right)$$

Two signs possible
⇒ Reversible

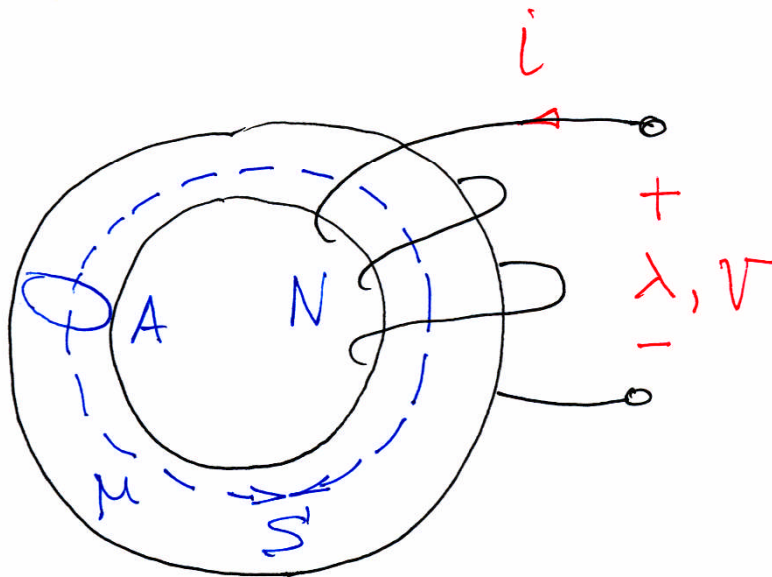
stored Energy

Capacitor Memory & Delay



- Charge and voltage depend on entire current history.
- Charge and voltage can not change abruptly without an infinite current.
- Delay is sometimes useful and sometimes annoying.

Ideal Inductor



Henries

$$\lambda = L i$$

↑ ↑
Webers Amps

$$L = \frac{\mu N^2 A}{S}$$

$$\lambda = \int_{-\infty}^t v dt \quad v = \frac{d\lambda}{dt} = \frac{d}{dt}(Li) = L \frac{di}{dt}$$

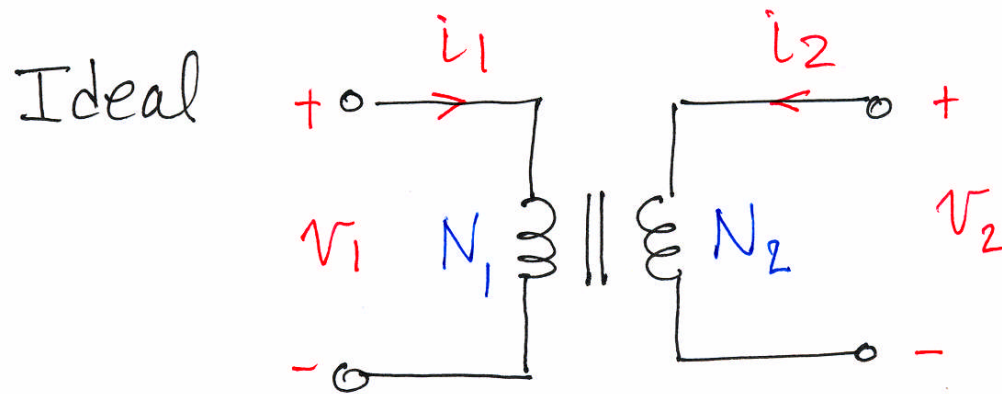
Memory 6.002

$$P = v i = L i \frac{di}{dt} = \frac{d}{dt} \left(\frac{1}{2} L i^2 \right)$$

Two Signs Possible
⇒ Reversible

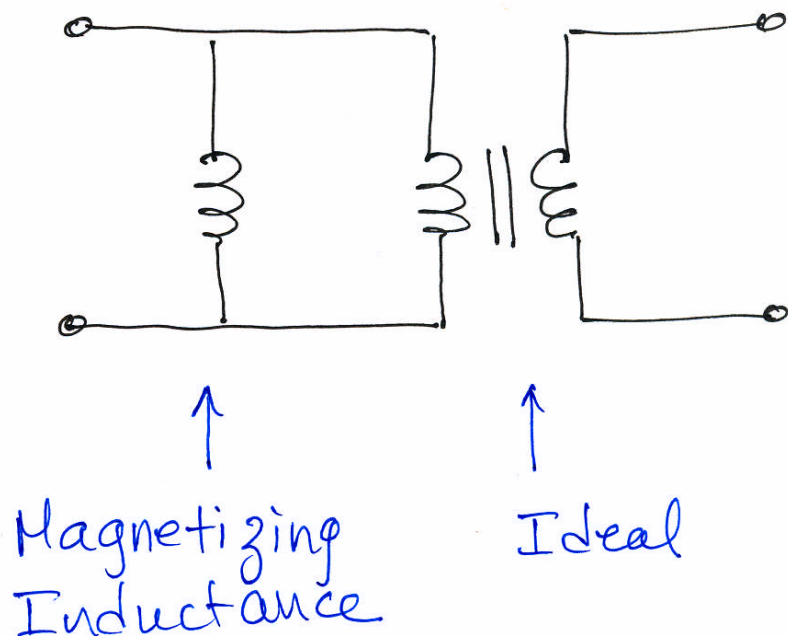
Stored Energy

Transformer

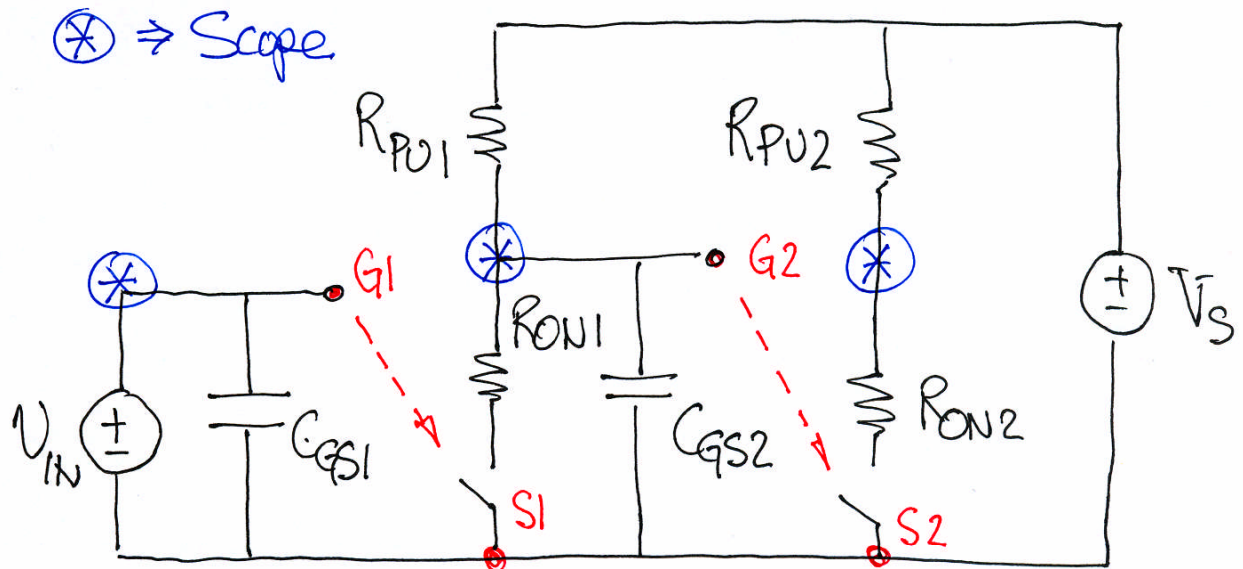


$$\frac{V_1}{V_2} = \frac{N_1}{N_2} \quad \frac{i_1}{i_2} = -\frac{N_2}{N_1} \quad \frac{P_1}{P_2} = -1$$

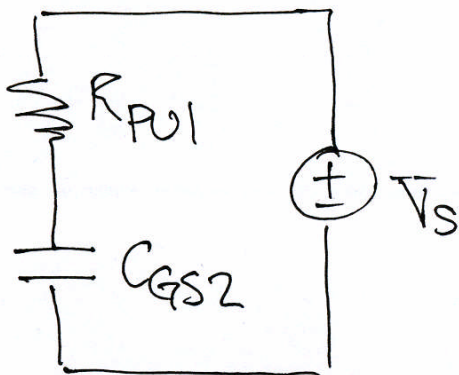
Non-Ideal
(Simplified)



Logic Delay Explained

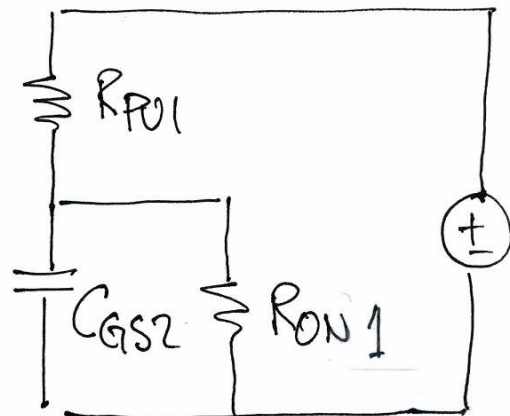


C_{GS2} Charge Up



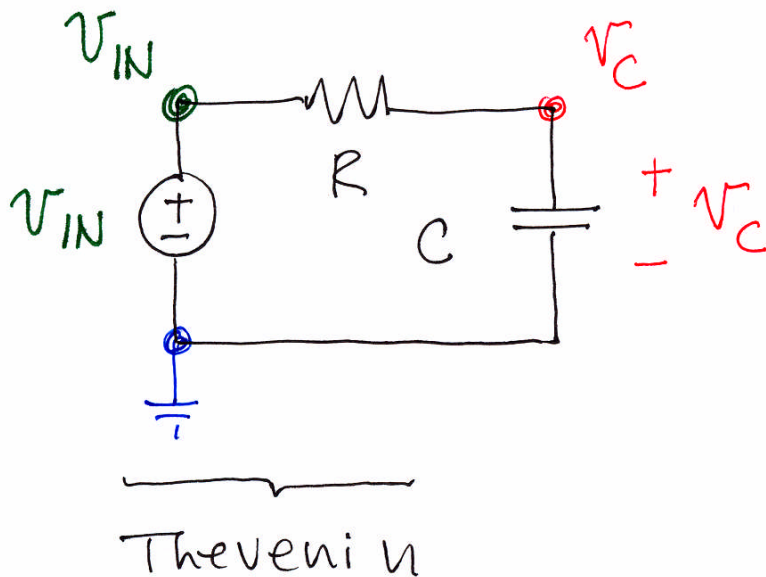
MOSFET 1 OPEN

C_{GS2} Charge Down



MOSFET 1 CLOSED

Transient Analysis I



Node Method $\Rightarrow \frac{V_C - V_{IN}}{R} + C \frac{dV_C}{dt} = 0$

Time $\left(RC \frac{dV_C}{dt} + V_C = V_{IN} \right)$

Well-Posed Problem $\Rightarrow$

- $V_C(0)$ Given
- $V_{IN}(t)$ Given
For $t \geq 0$

Transient Analysis II

Example: $V_C(0)$ Given & $V_N(t) \equiv V$ for $t \geq 0$

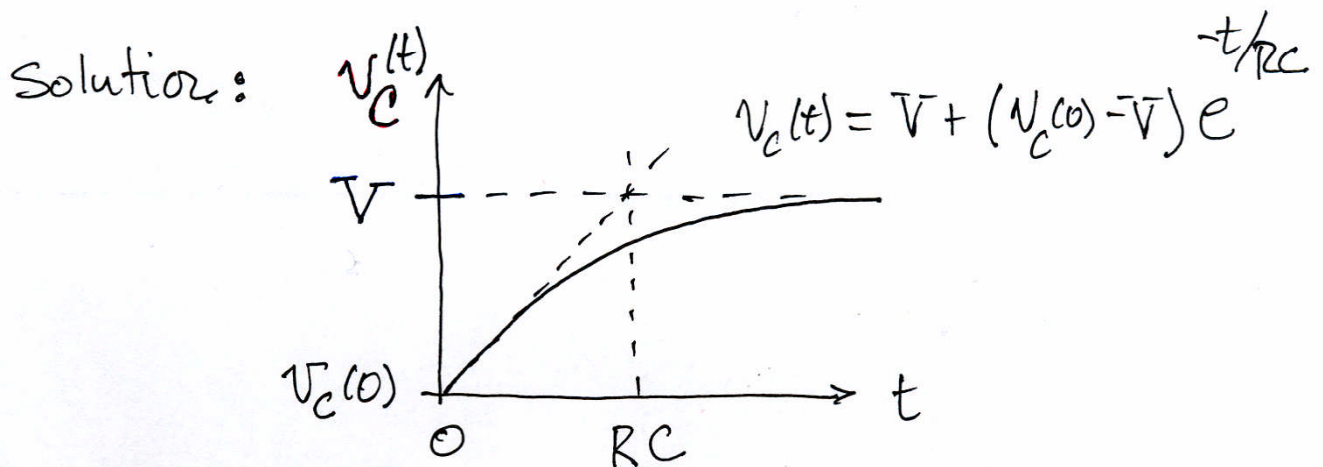
Solution: $V_C(t) = V_P(t) + V_H(t)$
Particular Homogeneous

Particular: $V_P(t) = \bar{V}$... By Inspection

Homogeneous: $RC \frac{dV_H(t)}{dt} + V_H(t) = 0$

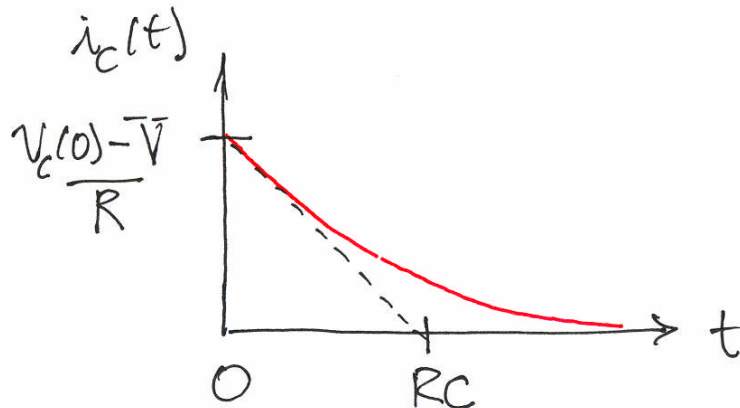
$$V_H(0) = V_C(0) - V_P(0) = V_C(0) - \bar{V}$$

$$V_H(t) = (V_C(0) - \bar{V}) e^{-t/RC}$$



Transient Analysis III

$$i_C(t) = C \frac{dV_C(t)}{dt} = \frac{V_C(0) - \bar{V}}{R} e^{-t/RC}$$



Short Times : Capacitor charge and voltage are approximately constant.
 $t \ll RC$

Capacitor $\approx$ short if $q(0) = 0$.

Example: $i_C(0) \approx \frac{\bar{V} - V_C(0)}{R}$.

Long Times: Capacitor current $\rightarrow 0$ and capacitor behaves as an open.
 $t \gg RC$

Example: $V_C \rightarrow \bar{V}$ and $i_C \rightarrow 0$.